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Topological Exciton Bands in Moiré Heterojunctions

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Moiré patterns are common in Van der Waals heterostructures and can be used to apply periodic potentials to elementary excitations. We show that the optical absorption spectrum of transition metal dichalcogenide bilayers is profoundly altered by long period moiré patterns that introduce twist-angle dependent satellite excitonic peaks. Topological exciton bands with non-zero Chern numbers that support chiral excitonic edge states can be engineered by combining three ingredients: i) the valley Berry phase induced by electron-hole exchange interactions, ii) the moiré potential, and iii) the valley Zeeman field.

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The properties of the van der Waals heterostructures formed by two-dimensional (2D) materials open up new strategies for materials property engineering. One increasingly important example, which has already been extensively explored in graphene on graphene and graphene on hexagonal boron nitride (hBN) heterostructures, is the possibility of using the relative orientation (twist) angle between two 2D crystals to tune electronic properties. For small twist angles and lattice-constant mismatches, heterostructures exhibits long period moiré patterns that can yield dramatic changes, for example by opening gaps at graphene's Dirac point [1, 2] and generating secondary Dirac points[3, 4]. In the presence of a strong magnetic field, the moiré pattern has enabled clear observations of Hofstadter-butterfly spectra and new fractional quantum Hall states [1, 4–6].

In this Letter, we study the influence of moiré patterns on collective excitations, focusing on the important case of excitons in the transition metal dichalcogenide (TMD) 2D semiconductors [7, 8] like MoS_2 and WS_2. Exciton features dominate the optical response of these materials because electron-hole pairs are strongly bound by the Coulomb interaction [9–12]. An exciton inherits a pseudospin-1/2 valley degree of freedom from its constituent electron and hole, and the exciton valley pseudospin can be optically addressed [13–16], providing access to the valley Hall effect [17] and the valley selective optical Stark effect [18, 19].

As in the case of graphene/hBN and graphene/graphene, a moiré pattern can be established in TMD bilayers by using two different materials with a small lattice mismatch, by applying a small twist, or by combining both effects. TMD heterostructures have been realized [20–22] experimentally and have already attracted great interest, for example, the observation of valley polarized interlayer excitons with long lifetimes [23], the theoretical prediction of multiply degenerate interlayer excitons [24], and the possibility of achieving spatially indirect exciton condensation [25, 26]. Our focus here is instead on the *intralayer* excitons which are more strongly coupled to light. As we explain below, the moiré pattern produces a periodic potential, mixing momentum states separated by moiré reciprocal lattice vectors and producing satellite optical absorption peaks that are revealing. The exciton energy-momentum dispersion can be measured by tracking the dependence of satellite peak energies on twist angle.

In monolayer TMDs, electron-hole exchange interactions lift valley degeneracy at finite momentum and endows a bright exciton [27, 28] with a unique 2π momentum-space Berry phase. The exchange interactions require a finite overlap between electron and hole wave functions and are therefore much weaker for interlayer excitons. We show that topological exciton bands characterized by quantized Chern numbers can be achieved by exploiting this momentum-space Berry phase in the presence of a periodic potential that creates exciton bands, and time-reversal symmetry breaking by a Zeeman field. All three ingredients are readily available in TMD bilayers. The bulk topological bands lead to chiral edge states, which support unidirectional transport of excitons optically generated on the edge. Our study therefore suggests a practical new route to engineer topological collective excitations which are actively sought[29–33] in several different contexts.

Exciton Potential Energy— For definiteness we consider the common chalcogen TMD bilayer MoX_2/WX_2 with a small twist angle θ and an in-plane displacement $\mathbf{d}$. TMDs with a common chalcogen (X) atom have small lattice mismatches ($\sim 0.1\%$), which we neglect to simplify calculations. Because of the van der Waals heterojunction character and relative band offsets, both conduction and valence bands of MoX_2 and WX_2 are weakly coupled across the heterojunction. The heterojunctions have two distinct stacking orders AA and AB, which are illustrated in Figs. 1(a) and 1(d). Both configurations have been experimentally realized [23, 34].

We start by analyzing the bilayer electronic structure at zero twist angle. Fully-relativistic density- functional-theory *ab initio* calculation is performed for crystalline

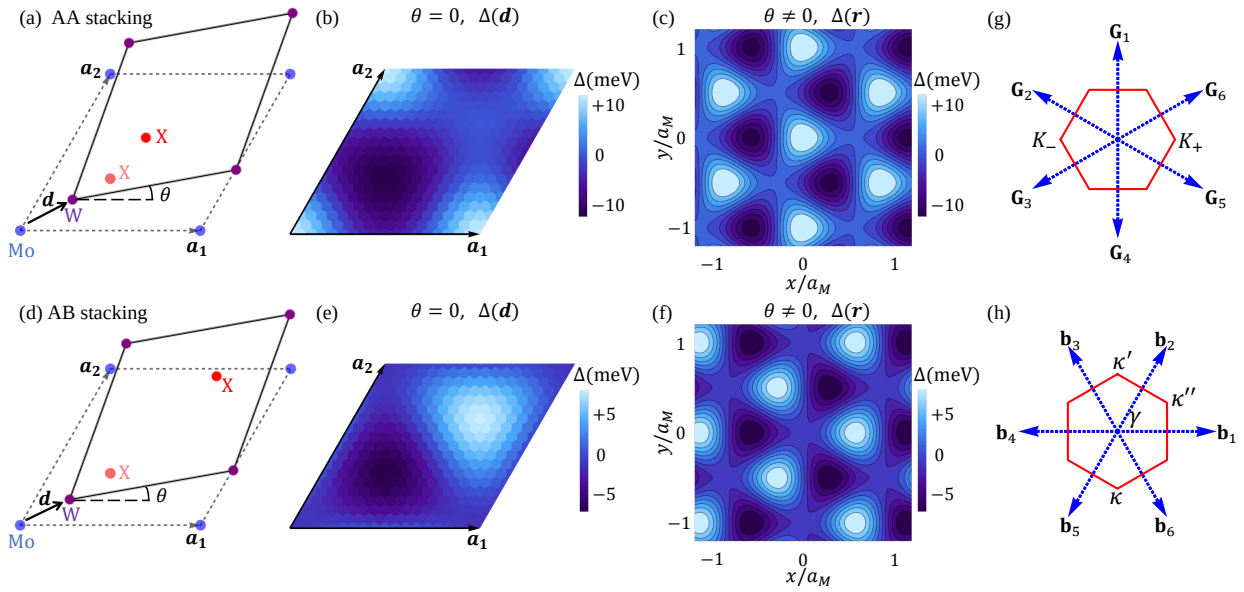

FIG. 1. (color online). (a) Illustration of AA stacking with a small twist angle θ and an in-plane displacement $\mathbf{d}$. (b) MoS_2 band gap as a function of $\mathbf{d}$ in AA stacked MoS_2/WS_2 bilayer with zero twist angle. (c) MoS_2 band gap as a function of position in AA stacked twisted MoS_2/WS_2. The spatial scale in this illustrations is the moiré period $a_M \sim a_0/\theta$. (d)-(f) Corresponding plots for AB stacking. (g) First-shell reciprocal lattice vectors $\mathbf{G}_j$ of a monolayer TMD triangular lattice and the corresponding Brillouin zone (red hexagon). (h) Moiré reciprocal lattice vectors and corresponding Brillouin zone

MoS_2/WS_2 ($\theta = 0°$) as a function of relative displacement $\mathbf{d}$. We used the local density approximation with optimized norm-conserving pseudopotentials [35, 36] as implemented in Quantum Espresso [37], and determined the orbital character of electronic bands using Wannier90 [38]. More details of the calculation are presented in the Supplemental Material [39]. Our primary interest here is intra-layer physics. Figs. 1(b) and 1(e) illustrate the $\mathbf{d}$ dependence of the energy gap at the $K_\pm$ points between states concentrated in the MoS_2 layer. The variation is a periodic function of $\mathbf{d}$ with the 2D lattice periodicity, and is adequately approximated by the lowest harmonic expansion:

$$\Delta(\mathbf{d}) \equiv E_g(\mathbf{d}) - \langle E_g \rangle \approx \sum_{j=1}^{6} V_j \exp(i\mathbf{G}_j \cdot \mathbf{d}), \quad (1)$$

where E_g is the intralayer band gap of MoS_2, $\langle E_g \rangle$ is its average over $\mathbf{d}$, and $\mathbf{G}_j$ is a one of the first-shell reciprocal lattice vectors illustrated in Fig. 1(g). The lattice's three-fold rotational symmetry leads to the constraint:

$$V_1 = V_3 = V_5,\ V_2 = V_4 = V_6. \quad (2)$$

Because Δ is real, we also have that $V_1 = V_4^*$. It follows that all six V_j are fixed by $V_1 = V\exp(i\psi)$. For MoS_2 on WS_2 we find that $(V, \psi) = (2.3\text{meV}, 30.8°)$ for AA stacking and $(1.4\text{meV}, 98.6°)$ for AB stacking. Because the band offset between the two layers can be modified by external electric fields, we expect that the values of these parameters can be tuned using gate voltages.

Rotation by angle θ transforms lattice vector $\mathbf{L}$ to $\mathbf{L}' = \mathcal{R}(\theta)\mathbf{L}$, where $\mathcal{R}(\theta)$ is the rotation matrix. For small twist angles, the relative displacement[40] between two layers near position $\mathbf{L}'$ is therefore,

$$\mathbf{d}(\mathbf{L}') = \hat{T}\mathbf{L}' = \hat{T}(\mathbf{L}' - \mathbf{L}) \approx \hat{T}(\theta\hat{z} \times \mathbf{L}'), \quad (3)$$

where the operator $\hat{T}$ reduces a vector to the Wigner-Seitz cell of the triangular lattice labeled by $\mathbf{L}$. In the limit of small θ, the displacement varies smoothly with position and we assume that its influence is local [41, 42]. Because the size of an exciton in TMDs ($\sim$ 1nm) is larger than the lattice constant scale, validating a $\vec{k}\cdot\vec{p}$ description, but smaller than moiré periods, we expect that the exciton binding energy will be accurately independent of position and that the variation of exciton energy will follow that of local band gap:

$$\begin{aligned}\Delta(\mathbf{r}) &\approx \Delta(\mathbf{d}(\mathbf{r})) \approx \sum_{j=1}^{6} V_j \exp(i\mathbf{G}_j \cdot \mathbf{d}(\mathbf{r})) \\ &\approx \sum_{j=1}^{6} V_j \exp(i\mathbf{G}_j \cdot (\theta\hat{z} \times \mathbf{r})) = \sum_{j=1}^{6} V_j \exp(i\mathbf{b}_j \cdot \mathbf{r}).\end{aligned} \quad (4)$$

Here $\Delta(\mathbf{r})$ acts as an exciton potential energy, and $\mathbf{b}_j = \theta\mathbf{G}_j \times \hat{z}$ defines the reciprocal lattice vectors of the moiré pattern. The band gap varies periodically in space due to the moiré pattern, as illustrated in Figs. 1(c) and 1(f). The moiré periodicity a_M is controlled by the twist angle: $a_M \approx a_0/\theta$, where a_0 is the lattice constant of a monolayer TMD.

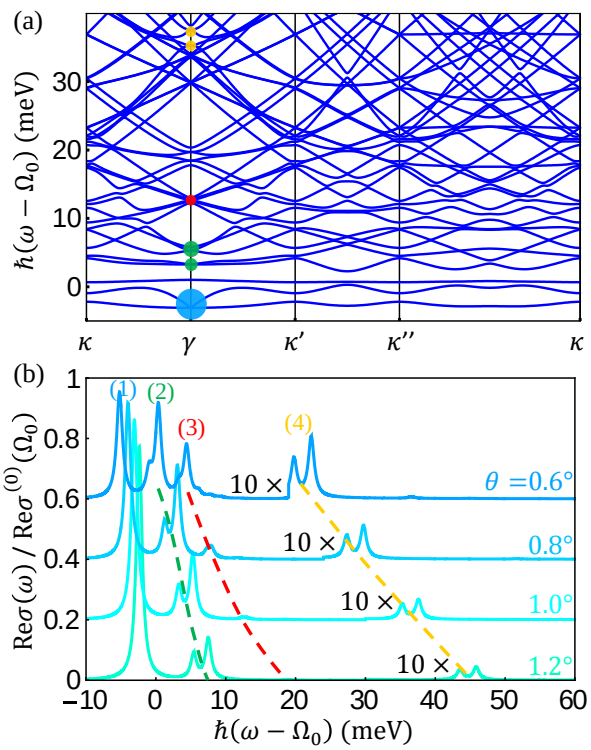

FIG. 2. (color online). (a) Exciton moiré bands along paths connecting high symmetry points in the MBZ. The twist angle θ used for this calculation is 1°. The sizes of the dots at the γ point correspond to the weight of state $|K_\pm^{(0)}\rangle$. The color of the dots encodes the main character of the states, with blue, red, green and yellow corresponding to character (1), (2), (3) and (4). See text. (b) Optical conductivity at several twist angles θ. Curves for different θ are shifted vertically for clarity and the dashed curves track the peak evolution. The two mini-peaks in (4) are amplified ten times. The broadening factor η is taken to be 0.5meV. The exciton potential parameters of AA stacked MoS_2/WS_2 were used in these calculations.

Optical response.— We study the A exciton, the lowest-energy bright exciton, in monolayer MoS_2. Its low-energy effective Hamiltonian [27, 28] is:

$$H_0 = (\hbar\Omega_0 + \frac{\hbar^2\mathbf{Q}^2}{2M})\tau_0 + J|\mathbf{Q}|\tau_0 + J|\mathbf{Q}|\big[\cos(2\phi_\mathbf{Q})\tau_x + \sin(2\phi_\mathbf{Q})\tau_y\big], \quad (5)$$

where $\mathbf{Q}$ is exciton momentum, $\hbar\Omega_0$ is its $\mathbf{Q}=0$ energy, $\hbar^2\mathbf{Q}^2/(2M)$ is its center-of-mass kinetic energy, and τ_0 and $\tau_{x,y}$ are respectively identity matrix and Pauli matrices in valley space. In Eq. (5), $\phi_\mathbf{Q}$ is the orientation angle of the 2D vector $\mathbf{Q}$, $J|\mathbf{Q}|\tau_0$ accounts for intravalley electron-hole exchange interactions, and the $\tau_{x,y}$ terms account for their intervalley counterparts. It follows that the A exciton has two energy modes,

$$E_\pm(\mathbf{Q}) = \hbar\Omega_0 + \frac{\hbar^2\mathbf{Q}^2}{2M} + J|\mathbf{Q}| \pm J|\mathbf{Q}|. \quad (6)$$

Note that E_+ has linear dispersion at small $|\mathbf{Q}|$, while the lower mode E_- is quadratic. From the *ab initio* GW Bethe-Salpeter calculation of Ref. [43] we obtain $M = 1.3m_0$ and $J = 0.4\text{eV}\cdot\text{Å}$, where m_0 is the free electron mass. Since the gap variation is guaranteed by time reversal symmetry to be identical for K_+ and K_- valleys, the exciton effective Hamiltonian of twisted bilayers is $H = H_0 + \Delta(\mathbf{r})\tau_0$.

We numerically diagonalize the Hamiltonian matrix using plane-wave expansion; exciton momentum reduced to the moiré Brillouin zone (MBZ) is a good quantum number. Fig. 2(a) illustrates the MoS_2 A exciton moiré bands for a 1° twist relative to WS_2. Smaller twist angles imply smaller MBZ dimensions and more moiré bands in a given energy window. For twist angles $\theta > 0.5°$, the wavelength (640nm) of light that excites A excitons greatly exceeds the moiré periodicity (<36nm). It follows that only excitons close to the MBZ center γ are optically active. We find that the real part of the optical conductivity:

$$\begin{aligned}\text{Re}\sigma(\omega) &= \frac{1}{\omega\mathcal{A}}\sum_n \big|\langle\chi_n|\hat{j}_x|G\rangle\big|^2\Gamma_1(\omega-\omega_n)\\ &\approx \frac{\big|\langle K_+^{(0)}|\hat{j}_x|G\rangle\big|^2}{\omega\mathcal{A}}\sum_n\Big|\sum_{\alpha=\pm}\langle\chi_n|K_\alpha^{(0)}\rangle\Big|^2\Gamma_1(\omega-\omega_n) \quad (7)\\ &\approx \frac{1}{2}\text{Re}\sigma^{(0)}(\Omega_0)\sum_n\Big|\sum_{\alpha=\pm}\langle\chi_n|K_\alpha^{(0)}\rangle\Big|^2\Gamma_2(\omega-\omega_n),\end{aligned}$$

where $\mathcal{A}$ is the system area, $\Gamma_m(\omega-\omega_n) = \eta^m/\big[\hbar^2(\omega-\omega_n)^2+\eta^2\big]$ and η is a broadening parameter. In Eq. (7) $\hat{j}_x$ is the current operator, $|G\rangle$ is the neutral semiconductor ground state, $|\chi_n\rangle$ and $\hbar\omega_n$ are the eigenstates and eigenvalues of the exciton moiré Hamiltonian at the γ point, $|K_\alpha^{(0)}\rangle$ is the valley K_α exciton eigenstate at zero twist angle, and $\text{Re}\sigma^{(0)}(\Omega_0)$ is the A exciton optical conductivity peak also at zero twist angle. The assumption underlying Eq. (7) is that only the $|K_\pm^{(0)}\rangle$ component in $|\chi_n\rangle$ contributes to the optical response. The final form for $\sigma(\omega)$ emphasizes that the exciton moiré potential has the effect of redistributing the A-exciton peak over a series of closely spaced sub-peaks.

Theoretical optical conductivities for a series of twist angles are illustrated in Fig. 2(b). Peaks labelled (1-4) (see caption) correspond respectively to bare excitons at zero momentum, E_- excitons at momentum $\mathbf{b}_i$, E_- excitons at momentum $\sqrt{3}\mathbf{b}_i\times\hat{z}$, and E_+ excitons at momentum $\mathbf{b}_i$. Without the moiré pattern there would only be one peak centered around frequency Ω_0; umklapp scattering off the moiré potentials unveils the formerly dark finite-momentum excitonic states. Both (2) and (4) give rise to two mini-peaks with a small energy splitting. As the twist angle decreases, $|\mathbf{b}_i|$ is reduced and the satellite peaks shift to lower energy and become stronger; for $\theta\sim 0.6°$ satellite peaks (2) and (3) have strength that is comparable to that of peak (1). Although peak (4) is weak, it decays more slowly compared to peak (3) when

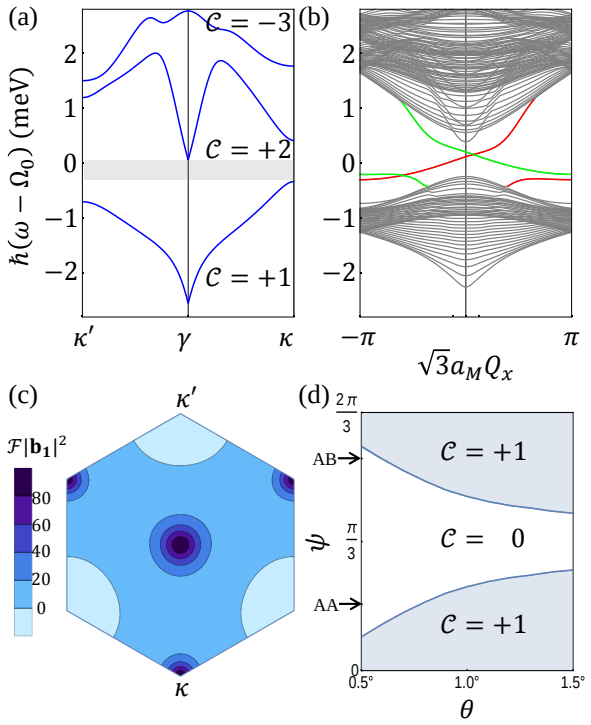

FIG. 3. (color online). (a) Topological exciton bands with quantized Chern numbers $\mathcal{C}$ for twist angle $\theta = 1^\circ$. The grey bar identifies the gap between the first and second exciton moiré band. (b) Stripe geometry quasi-1D bands for the same twist angle, an extended edge along the x direction, and finite width in the y direction. The red and green lines show the dispersions of chiral exciton states that are localized on opposite edges of the stripe. (c) Berry curvature $\mathcal{F}$ of the first band in (a). $\mathcal{F}$ is calculated using the Kubo formula expression. In (a), (b) and (c), h_z is 1.5meV, and $(V,\ \psi)$=(1.4meV, 98.6°), the parameter values for AB stacked MoS_2/WS_2. (d) Chern number $\mathcal{C}$ of the first exciton moiré band as a function of θ and ψ with $(V,\ h_z)$ fixed at (1.4meV, 1.5meV). The arrows indicate the value of ψ in AA and AB stacked MoS_2/WS_2. Adding $2\pi/3$ to ψ leads to a spatial translation of the moiré pattern. It follows that $\mathcal{C}$ is a periodic function of ψ with periodicity $2\pi/3$.

θ increases. The energy difference between peak (2) and (4) provides a direct measurement of the electron-hole exchange interaction strength.

Topological excitons.—The intervalley exchange interaction acts as an in-plane valley-space pseudo-magnetic field which rotates by 4π when the momentum encloses its origin once. This non-trivial winding number can be used to engineer topological exciton bands when combined with the moiré superlattice potential , which provides a finite Brillouin zone and an energy gap above the lowest exciton band at every $\mathbf{Q}$ point in the MBZ except γ point. An external Zeeman term $h_z\tau_z$ can further split the degeneracy at γ. A Zeeman term of this form has been experimentally realized in monolayer TMD by applying a magnetic field [44–46] and by using a valley selective optical Stark effect [18, 19]. The topology of the exciton bands is characterized by Berry curvature $\mathcal{F}$ and Chern number $\mathcal{C}$, just as in the electronic case:

$$\mathcal{F}_n(\mathbf{Q}) = \hat{z}\cdot\nabla_{\mathbf{Q}}\times\left[i\langle\chi_n(\mathbf{Q})|\nabla_{\mathbf{Q}}|\chi_n(\mathbf{Q})\rangle\right],$$
$$\mathcal{C}_n = \int_{\mathrm{MBZ}}\frac{d^2\mathbf{Q}}{2\pi}\mathcal{F}_n(\mathbf{Q}), \tag{8}$$

where $|\chi_n(\mathbf{Q})\rangle$ represents the nth eigenstate of Hamiltonian H at momentum $\mathbf{Q}$. Fig. 3(a) presents our results for the topological properties of moiré exciton bands in AB stacked MoS_2/WS_2. We find that the first exciton band possesses Chern number +1, and that it is isolated from other bands by global energy gap. The corresponding Berry curvature $\mathcal{F}$ has hot spots around the γ, κ, and κ' points in the MBZ as illustrated in Fig. 3(c). The Berry curvature $\mathcal{F}$ around the γ is simply understood in terms of the valley Berry phase induced by the exchange interaction, and its sign is determined by that of h_z. On the other hand, the peak in $\mathcal{F}$ around the κ and κ' point is related to avoided band crossings, and is sensitive to ψ, the phase of V_1. Fig. 3(d) shows the Chern number of the first band as a function of ψ and twist angle θ with $(V,\ h_z)$ fixed to (1.4meV, 1.5meV). Along the phase boundary lines at which the Chern number changes, the energy gaps at κ or κ' close. Because there is a large parameter space with a finite Chern number, we expect that topological exciton bands appear routinely in TMD bilayers.

We have confirmed the presence of the chiral excitonic edge states expected for topological bands by studying the energy spectrum of a finite-width stripe [39], as illustrated in Fig. 3(b). These states provides a unidirectional excitonic transport channel. It can be identified experimentally by applying spatially resolved photoluminescence or absorption spectroscopy to a TMD bilayer which is pumped and probed at a frequency in the Zeeman-field induced gap by a laser spot localized near one edge.

In summary, intralayer excitons in a twisted TMD bilayer exhibit rich phenomena enabled by the moiré pattern, including satellite excitonic peaks in optical absorption peaks that are tunable by varying twist angle. The moiré superlattice potential, the exciton Zeeman field, and the electron-hole exchange induced valley Berry phase can in combination give rise to topological exciton bands. Our analysis points to a practical strategy to realize topological excitons.

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